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# Thermoelectric properties of *n*-type cobalt doped chalcopyrite $\text{Cu}_{1-x}\text{Co}_x\text{FeS}_2$ and *p*-type eskebornite $\text{CuFeSe}_2$

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## Abstract

Chalcopyrite  $\text{CuFeS}_2$  has been recently suggested as a promising thermoelectric material. In the present paper, the transport properties – electrical resistivity  $\rho$  and Seebeck coefficient  $S$  – of the *n*-type  $\text{CuFeS}_2$  chalcopyrite and the *p*-type  $\text{CuFeSe}_2$  eskebornite have been measured. Very different groundstates are evidenced with a semimetallic behavior concomitant to a metal-like  $S(T)$  curve for  $\text{CuFeS}_2$  whereas  $\text{CuFeS}_2$  is a semiconductor with much larger  $|S|$  values. For that reason, charge creation by  $\text{Co}^{2+}$  for  $\text{Cu}^+$  substitution in  $\text{CuFeS}_2$  has been performed. The veracity of the Co for Cu substitution for  $x \leq 0.10$  in  $\text{Cu}_{1-x}\text{Co}_x\text{FeS}_2$  chalcopyrite has been confirmed by EDS analyses, coupled to electron diffraction, with a transmission electron microscope. Also, this study demonstrates the existence of twinning domains. The compounds corresponding to the best compositions in terms of power factor have been densified by Spark Plasma Sintering for thermal conductivity measurements. A maximum  $ZT$  value up to 0.22 at 675 K for  $\text{Cu}_{0.96}\text{Co}_{0.04}\text{FeS}_2$  has been obtained.

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**Keywords:** Chalcogenides; Thermoelectric material; Thermal conductivity

## 1. Introduction

In the past few years, the  $\text{CuFeS}_2$  chalcopyrite has been considered as a potential *n*-type material for thermoelectric application [1–5]. The thermoelectric efficiency of a material defined by its figure of merit  $ZT$  is equal to  $\alpha^2 T / \rho(\kappa_{el} + \kappa_{lat})$ , where  $T$  is the absolute temperature,  $\alpha$  the Seebeck coefficient,  $\rho$  the electrical resistivity,  $\kappa_{el}$  the electronic contribution to the thermal conductivity and  $\kappa_{lat}$  the thermal conductivity of the lattice (phonons) [6,7].  $ZT$  can also be deduced from the power factor,  $PF = \alpha^2 / \rho$ , by the relation:  $ZT = PF * T / (\kappa_{el} + \kappa_{lat})$ . In that respect, the high PF value

reported for doped  $\text{CuFeS}_2$  [1–5] makes this material attractive, especially if one considers that it is made of cheap and abundant elements as compared to other recently reported semiconductors crystallizing also in the chalcopyrite structure [8–10]. In addition,  $\text{CuFeS}_2$  is an antiferromagnet ( $T_N = 823$  K) [11], and it was proposed that the spins could play a role on the transport properties [2]. Also, there exists a structural transition close to  $T_N$  from the tetragonal space group of the chalcopyrite to a cubic zinc blende structure above  $T_N$  in which the Cu and Fe cations are disordered over the tetrahedral crystallographic sites [12].

This situation motivated us to study the effect of carrier doping by substituting a magnetic cation to optimize its thermoelectric properties. In the same time, the *p*-type counterpart  $\text{CuFeSe}_2$  has also been synthesized and its transport properties measured. Also  $\text{CuFeS}_2$  and  $\text{CuFeSe}_2$  have similar 1:1:2 atomic contents, they crystallize in different structures [13]. The latter can be described by a tetragonal close-packed

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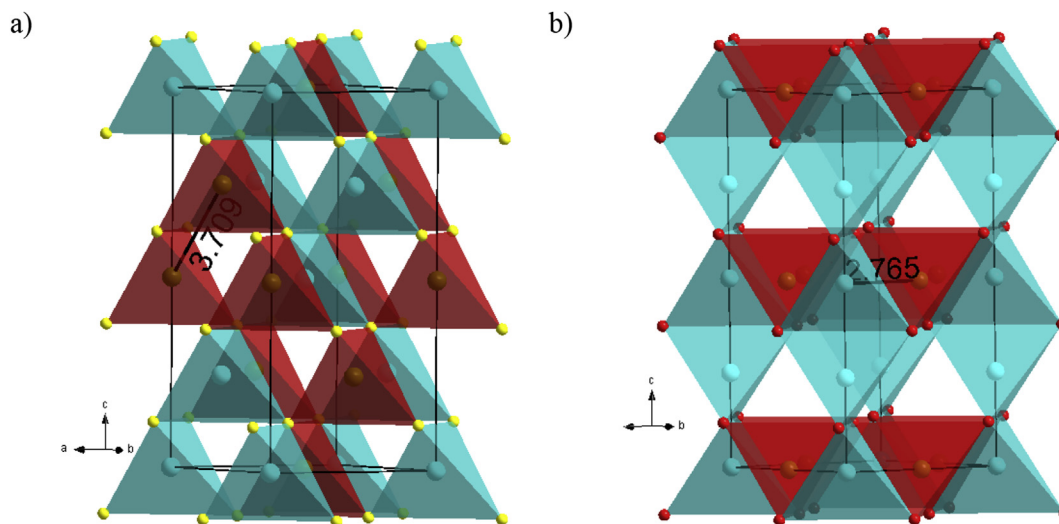


Fig. 1. Views of the crystals structures of (a)  $\text{CuFeS}_2$  and (b)  $\text{CuFeSe}_2$ . Shortest metal–metal distances are shown for both structures.

stacking of  $\text{S}^{2-}$  or  $\text{Se}^{2-}$  anions in which the Cu and Fe cations are distributed differently over the empty tetrahedral sites (Fig. 1). As a consequence, even if the sulfur coordination of Cu and Fe is tetrahedral, the metal–metal distance shrinks by almost 1 Å as one goes from  $\text{CuFeS}_2$  or  $\text{CuFeSe}_2$ . This is believed to explain the semimetallic character of  $\text{CuFeSe}_2$  as compared to the semiconducting behavior of  $\text{CuFeS}_2$ . For the latter, it must be pointed out that it can be classified as a “Haldane-Anderson” type insulator with a strong d-p hybridization, 80% of the holes of  $\text{Fe}^{3+}$  in the formally written  $\text{Cu}^+\text{Fe}^{3+}\text{S}_2^{2-}$  formula being transferred on sulfur anions [14].

In the following, the properties of  $\text{CuFeSe}_2$  and  $\text{CuFeS}_2$  are compared and the effect of Co doping in  $\text{CuFeS}_2$  is studied. A ZT value reaching  $\text{ZT} = 0.22$  at 675 K is achieved for  $\text{Cu}_{0.94}\text{Co}_{0.06}\text{FeS}_2$ .

## 2. Experimental

The  $\text{Cu}_{1-x}\text{Co}_x\text{FeS}_2$  and  $\text{CuFeSe}_2$  polycrystalline samples were first prepared by mixing Cu, Fe, Co and S/Se in the appropriate ratio. After sealing the cold pressed powder in a close ampoule, the latter was heated at 600 °C for 48 h. For some compositions, the obtained powder was then sintered by SPS using a maximum temperature of 500 °C for 30 min under a pressure of 70 Mpa, followed by cooling in 20 min. The density of these SPS pucks was found to be greater than 90%. The crystallographic quality was determined by using powder X-ray diffraction data. Rietveld refinement of the highly densified sample was performed with the FULLPROF program using pseudo-Voigt peak shape function. Transmission Electron Microscopy (TEM) measurements, including high resolution TEM (HRTEM) and electron diffraction (ED) studies, were performed using Tecnai G2 30 UT ( $\text{LaB}_6$ ) microscope operated at 300 kV and having 0.17 nm point resolution. This microscope is equipped with a EDAX detector for EDX analysis. TEM specimens made of powders were prepared by crushing the samples in agate mortar, dissolving in

methanol and depositing on Ni holey carbon grid. Transport option of a physical properties measurement system (PPMS from Quantum Design) was also used to measure the electrical resistivity ( $\rho$ ) and a home-made puck was used to measure the Seebeck coefficient ( $S$ ), (steady-state technique) up to 300 K in the same cryostat. For  $T > 300$  K, a Ulvac Riko ZEM3 system working under a helium partial pressure was used to measure  $\rho$  and  $S$ . The thermal conductivity  $\kappa$  was obtained for  $T > 300$  K by combining thermal diffusivity and heat capacity data measured with Netzsch systems operating in  $\text{N}_2$  flow.

## 3. Results

### 3.1. Structural characterizations

The room temperature powder X-ray diffraction patterns (Fig. 2) of  $\text{CuFeSe}_2$  and  $\text{Cu}_{1-x}\text{Co}_x\text{FeS}_2$  evidence first the

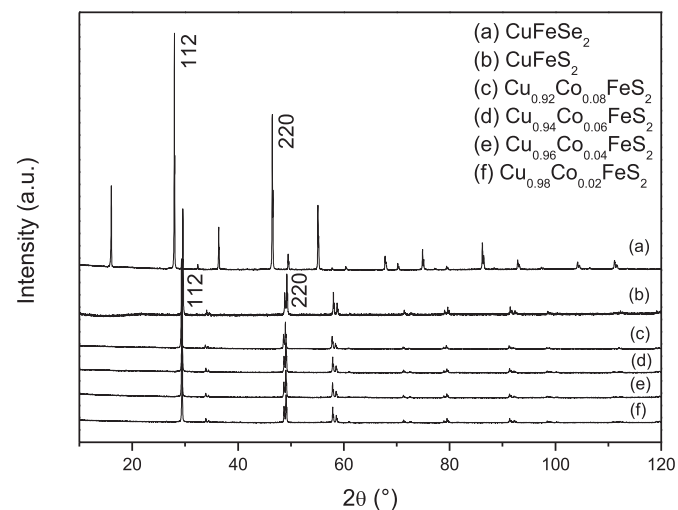


Fig. 2. Powder diffraction patterns of  $\text{CuFeCh}_2$  samples obtained after solid state reaction.  $hkl$  index are given for the main peaks of both structure type.

structural difference between the eskebornite ( $P-42c$  space group) and chalcopyrite ( $I-42d$ ). No extra peaks could be hardly observed for both  $\text{CuFeSe}_2$  and  $\text{CuFeS}_2$  (Fig. 2a and b)). For  $\text{Cu}_{1-x}\text{Co}_x\text{FeS}_2$  by varying  $x$  by 0.02 from  $x = 0.00$  to 0.20, it turns out that impurities (mainly  $\text{CoS}_2$ ) were detected from  $x = 0.10$ . For that reason, the study was limited to  $x \leq 0.08$ . Also, as the  $\text{Fe}_{1-x}\text{Co}_x\text{S}_2$  solid solution with the pyrite structure exists [15], even if Fe or Co divalent cations are in octahedral coordination in that structure, attempts to substitute Co for Fe in  $\text{CuFeS}_2$  were made. However, extra peaks were always detected even for the lowest content corresponding to the nominal “ $\text{CuFe}_{0.98}\text{Co}_{0.02}\text{S}_2$ ” formula. This indicates that the divalent oxidation state of cobalt being more stable in sulfides,  $\text{Co}^{2+}$  cannot substitute easily  $\text{Fe}^{3+}$  in

“ $\text{Cu}^+\text{Fe}^{3+}\text{S}_2^{2-}$ ”, but, rather, it substitutes for monovalent copper as it was previously shown for other substituting elements as  $\text{Zn}^{2+}$  in  $\text{Cu}_{1-x}\text{Zn}_x\text{FeS}_2$  or for the series  $\text{Cu}_{1-x}\text{Fe}_{1+x}\text{S}_2$  [2–5]. According to the limited solubility of Co for Cu (8% at maximum) determined from X-ray diffraction by detection of secondary phases, it must be also pointed out that all our attempts to make copper deficient  $\text{Cu}_{1-x}\text{FeS}_2$  compounds led to the formation of impurities from the powder X-ray diffraction pattern. In order to confirm the veracity of the Co for Cu substitution, electron diffraction studies, performed with a transmission electron microscope coupled to EDX, and HRTEM imaging were all made for the  $x = 0.06$  “SPS” sample (Fig. 3). The local composition analysis using EDX, in the accuracy of the techniques,

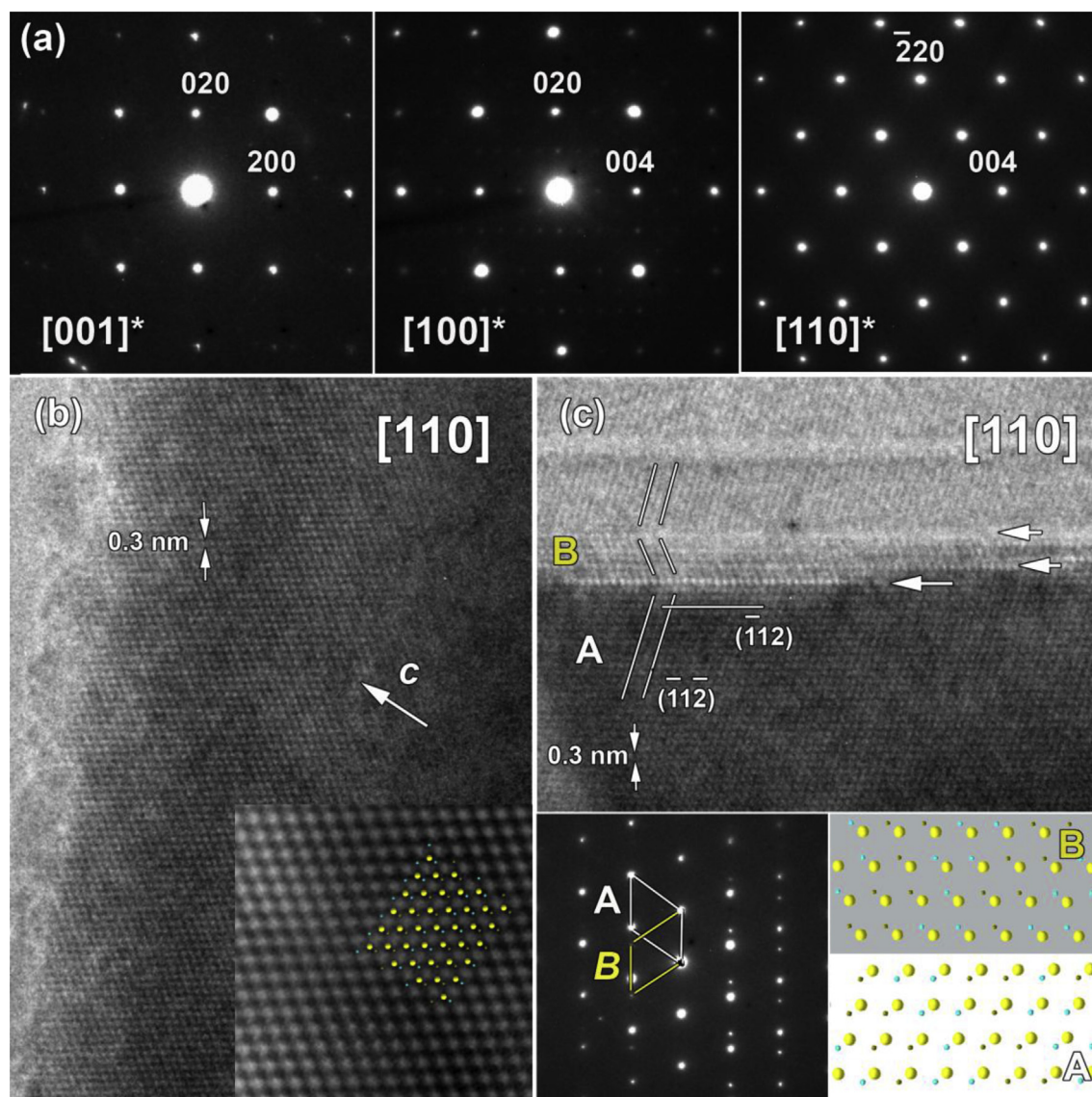


Fig. 3. (a) ED patterns of “SPS”  $\text{Cu}_{0.94}\text{Co}_{0.06}\text{FeS}_2$  from main zone axis:  $[001]^*$ ,  $[100]^*$  and  $[110]^*$  (b) HRTEM image of  $\text{Cu}_{0.94}\text{Co}_{0.06}\text{FeS}_2$  along  $[110]$  zone axis with an overlay model given as insert (blue –Cu/Co, green – Fe, yellow – S). Note that under present image conditions, the bright dots correspond to the voids and the dark ones to the atoms position. (c)  $[110]$  HRTEM image of twinned area and corresponding ED pattern. Twinning planes are marked by white arrows. A structural model of the twin boundary is given as insert (right bottom corner) where two twin variants are marked as A and B, correspondingly.



performed on several tenths of microcrystallites confirms that cobalt is definitely present within each crystallites of  $\text{Cu}_{1-x}\text{Co}_x\text{FeS}_2$  with an estimated cation composition:  $0.94 \pm 0.02:0.06 \pm 0.02:1:00 \pm 0.02$  in good correspondence with the cation content in the nominal  $\text{Cu}_{0.94}\text{Co}_{0.06}\text{FeS}_2$  formula. The ED patterns collected from main zone axis shown in Fig. 3a can be indexed based on tetragonal  $I-42d$  structure (SG 122,  $a = 0.53 \text{ nm}$ ,  $c = 1.042 \text{ nm}$ ) of  $\text{CuFeS}_2$  [16]. The ED patterns and corresponding HRTEM images (Fig. 3b) show that the compound is well crystallized. A comparison of the experimental and calculated HRTEM images (not shown here) shows, that under present experimental conditions, the columns of atoms are imaged as the darkest regions. Twinning was the only kind of defects which was observed. The HRTEM image and corresponding ED pattern of a twinned area are shown in Fig. 3c. The ED pattern is the superposition of two  $\text{Cu}_{1-x}\text{Co}_x\text{FeS}_2$  slices (marked in the figure as A and B) and exhibits splitting of diffraction spots which is typical of twinned structure. From the ED pattern, the twinning plane is  $\{112\}$ . The twin slices are limited by sharp coherent twin boundaries parallel to the  $(-112)$  plane. The rows of the bright dots (marked by white arrowheads) indicate the twin boundaries. The dot brightness is higher than that of the matrix suggesting different atomic arrangement along twin boundaries. From the crystallographic viewpoint, such twinning is often observed in cubic phases. As the present material exhibits a transition from the  $I-42d$  tetragonal structure at room temperature to an  $F-43m$  cubic structure at high temperature ( $\sim 800 \text{ K}$ , [12]), i.e. such a kind of twinning is consistent with the fact that its RT structure is close to cubic. Such local antiphase domains of small size might also play a role in the phonon scattering as it was invoked for the “TAGS” thermoelectric materials [17].

### 3.2. Physical properties

#### 3.2.1. $\text{CuFeSe}_2$ and $\text{CuFeS}_2$ : evidence for very different groundstates

The measurements of electrical resistivity ( $\rho$ ) and Seebeck coefficient ( $S$ ) evidence the very different groundstates for the sulfide and selenide (Fig. 4(a)).  $\text{CuFeSe}_2$  exhibits a semi-metallic character with  $\rho_{300\text{K}} = 0.35 \text{ }\Omega\cdot\text{cm}$  which is consistent with the already reported data of the literature [13]. Its  $S(T)$  curve is linear with  $S > 0$  values, indicating the  $p$ -type nature of the transport as expected for a metal-like behavior.  $S$  increases with  $T$  up to  $S \approx +15 \text{ }\mu\text{V}\cdot\text{K}^{-1}$  at  $300 \text{ K}$ , which remains a modest value. This metallic like behavior is in marked contrast with the semiconducting behavior of  $\text{CuFeS}_2$  which  $S(T)$  values are negative, indicating a  $n$ -type behavior, and which absolute values,  $S_{300\text{K}} \approx -350 \text{ }\mu\text{V}\cdot\text{K}^{-1}$ , are much larger than those of  $\text{CuFeSe}_2$ . It must be emphasized that the concomitant decrease of both electrical conductivity and Seebeck coefficient as temperature decreases supports a behavior near the intrinsic one as discussed in Ref. [5]. These  $\rho$  and  $S$  values lead to very different values for the power factor,  $\text{PF}(275 \text{ K}) = 1.10^{-5} \text{ W}\cdot\text{K}^{-2}\cdot\text{m}^{-1}$  and  $5.10^{-8} \text{ W}\cdot\text{K}^{-2}\cdot\text{m}^{-1}$  for  $\text{CuFeS}_2$  and  $\text{CuFeSe}_2$ , respectively (Fig. 4(b)). Thus, the

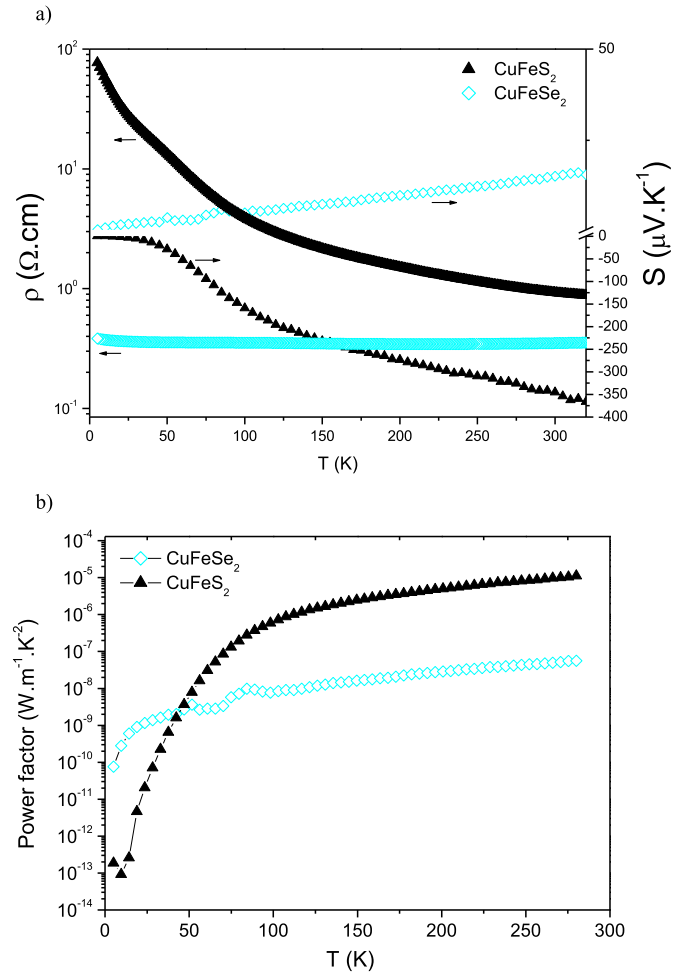


Fig. 4. (a) Temperature ( $T$ ) dependence of the electrical resistivity ( $\rho$ ), left y-axis and Seebeck coefficient ( $S$ ), right y-axis of  $\text{CuFeSe}_2$  and  $\text{CuFeS}_2$  measured at low temperature (b)  $T$  dependence of the power factor of  $\text{CuFeSe}_2$  and  $\text{CuFeS}_2$  measured at low  $T$ .

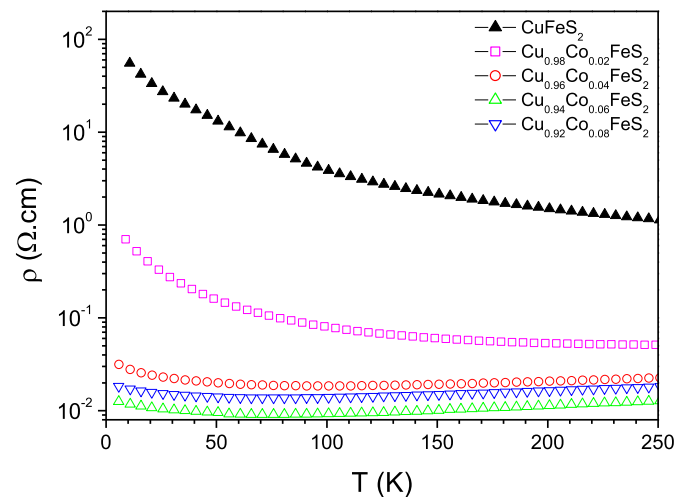


Fig. 5.  $T$  dependence of  $\rho$  measured at low temperature on samples prepared by solid state reaction and cold pressed.

metallic behavior of  $\text{CuFeS}_2$ , which might be linked to the metal bonding created by short intermetallic distances in the eskebornite structure, is redhibitory for the use of  $\text{CuFeS}_2$  as a thermoelectric material. This motivated the study of Co doping in the  $\text{CuFeS}_2$  chalcopyrite only.

### 3.2.2. $\text{Cu}_{1-x}\text{Co}_x\text{FeS}_2$

At first, low temperature measurements have been carried out on cold pressed samples, and the corresponding  $\rho(T)$  curves are plotted in Fig. 5. As compared to  $\text{CuFeS}_2$ , the cobalt substitution for copper induces a decrease of electrical resistivity, to reach a metallic behavior over a broad range of temperature for  $x \geq 0.04$ . The resistivity of Co-doped samples decreases with the increase of cobalt amount from  $\text{Cu}_{0.98}\text{Co}_{0.02}\text{FeS}_2$  to  $\text{Cu}_{0.94}\text{Co}_{0.06}\text{FeS}_2$ . For the  $x = 0.08$  sample, the resistivity keeps similar values as for  $\text{Cu}_{0.94}\text{Co}_{0.06}\text{FeS}_2$ , which suggests a limit of Co substitution close to 6% in good agreement with the solubility limit determined by powder X-ray diffraction. This  $\rho$  decrease with the increase of the Co amount suggests the creation of charge carriers resulting from a  $\text{Co}^{2+}$  for  $\text{Cu}^+$  aliovalent substitution.

The low temperature dependence of  $S$  (Fig. 6) confirms that scenario. All the  $\text{Cu}_{1-x}\text{Co}_x\text{FeS}_2$  samples show a  $n$ -type behavior with absolute value of Seebeck coefficients that decrease with  $x$  increasing. The lack of linear  $S\alpha T$  regime is consistent with a behavior of degenerate semiconductor. The corresponding PF values obtained from these measurements are shown in Fig. 7. The highest PF values at 275 K are obtained for the  $\text{Cu}_{0.96}\text{Co}_{0.04}\text{FeS}_2$  and  $\text{Cu}_{0.94}\text{Co}_{0.06}\text{FeS}_2$  samples, with  $\text{PF} = 1.75 \cdot 10^{-4} \text{ W.K}^{-2}.\text{m}^{-1}$  and  $\text{PF} = 2.25 \cdot 10^{-4} \text{ W.K}^{-2}.\text{m}^{-1}$ , respectively. Therefore samples of both compositions were densified by SPS to estimate their thermoelectric performances.

The high temperature dependence of  $S$  (Fig. 8) for these “SPS” samples exhibits an increase of the absolute value of  $S$

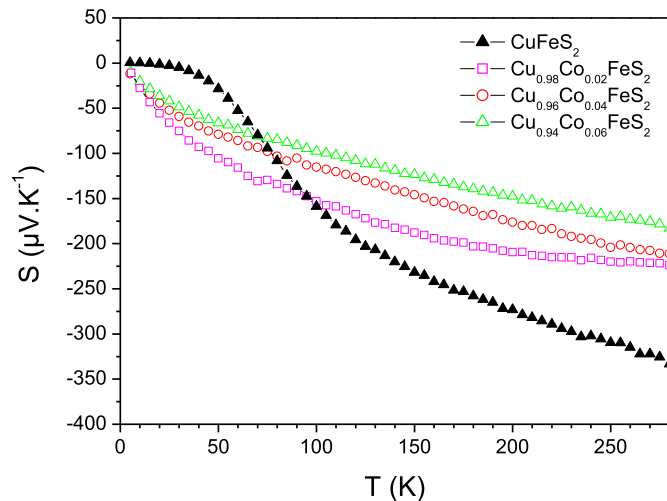


Fig. 6.  $T$  dependence of  $S$  measured at low temperature on samples prepared by solid state reaction and cold pressed.

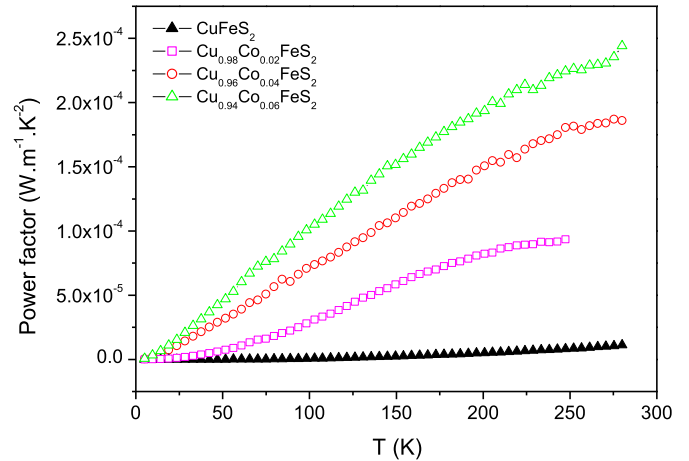


Fig. 7.  $T$  of the power factor measured at low  $T$  on samples prepared by solid state reaction and cold pressed.

with  $T$ , reaching at 675 K maximal values of  $240 \mu\text{V/K}$  and  $275 \mu\text{V/K}$  for  $\text{Cu}_{0.94}\text{Co}_{0.06}\text{FeS}_2$  and  $\text{Cu}_{0.96}\text{Co}_{0.04}\text{FeS}_2$ , respectively. It must be pointed out that the  $S$  (275 K) values are in good correspondence with those collected on cold pressed samples (Figs. 6 and 8). This supports the fact that the overall stoichiometry is preserved during the SPS process, so that no  $S$  deficiency as for the  $\text{CuFeS}_{2-x}$  series [1] is created.

The corresponding  $\rho(T)$  curves are plotted in Fig. 8 (left y-scale) for the same  $T$  range. For both samples densified by SPS, the curves confirm a metallic behavior with  $\rho$  increasing with  $T$  up to  $\sim 600$  K. Above  $\sim 600$  K,  $\rho$  starts to saturate and then to decrease in the case of  $\text{Cu}_{0.94}\text{Co}_{0.06}\text{FeS}_2$  (Fig. 8). This might be ascribed to the beginning of the structural transition which is complete at  $\sim 800$  K [12]. Interestingly, the densification by SPS induces a decrease of the electrical resistivity: for  $\text{Cu}_{0.94}\text{Co}_{0.06}\text{FeS}_2$  at 275 K,  $\rho \approx 5.4 \cdot 10^{-3} \Omega.\text{cm}$  for the SPS prepared dense sample against  $\rho \approx 1.3 \cdot 10^{-2} \Omega.\text{cm}$  for the cold pressed one (Fig. 4). Consequently, as  $S$  is kept unchanged and

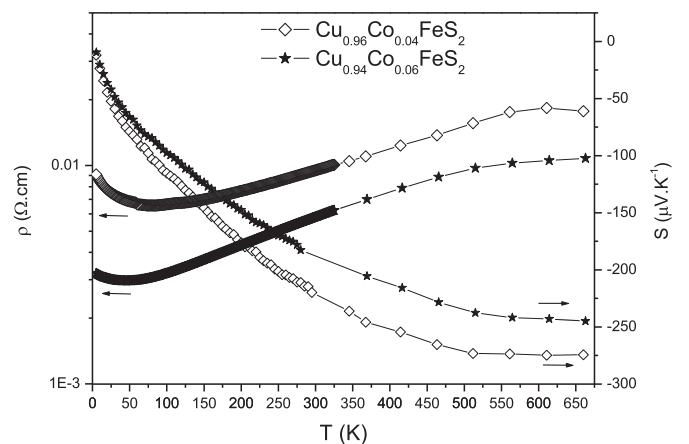


Fig. 8.  $T$  dependence of both  $S$  and  $\rho$  at high  $T$  for both samples densified by SPS,  $\text{Cu}_{0.96}\text{Co}_{0.04}\text{FeS}_2$  and  $\text{Cu}_{0.94}\text{Co}_{0.06}\text{FeS}_2$ .

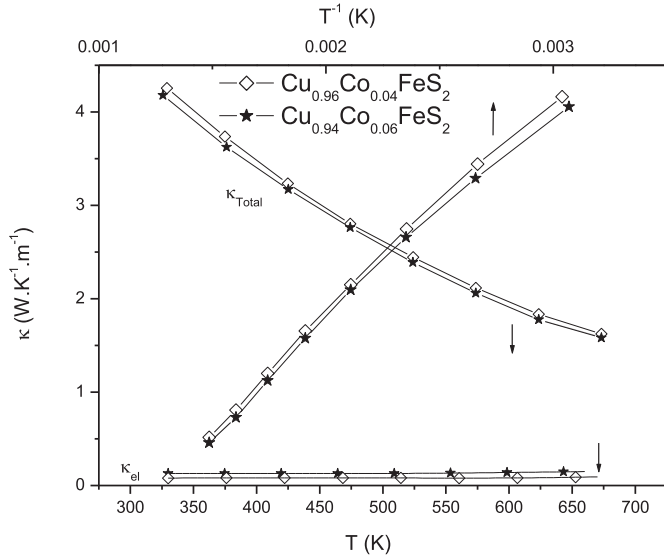


Fig. 9.  $T$  and  $T^{-1}$  dependence of the thermal conductivity  $\kappa$  at high  $T$  for  $\text{Cu}_{0.96}\text{Co}_{0.04}\text{FeS}_2$  and  $\text{Cu}_{0.94}\text{Co}_{0.06}\text{FeS}_2$  densified by SPS.

$\rho$  decreases, the PF values are enhanced to reach maximum values of  $\text{PF} \approx 5.5 \cdot 10^{-4} \text{ W.m}^{-1}.\text{K}^{-2}$  and  $\text{PF} \approx 6.2 \cdot 10^{-4} \text{ W.m}^{-1}.\text{K}^{-2}$  at 370 K for  $\text{Cu}_{0.94}\text{Co}_{0.04}\text{FeS}_2$  and  $\text{Cu}_{0.94}\text{Co}_{0.06}\text{FeS}_2$ , respectively.

The thermal conductivities  $\kappa$  as a function of  $T$  for these SPS prepared samples are presented in Fig. 9. The  $\kappa$  value decreases as  $T$  increasing, to reach values as low as  $\kappa_{600\text{K}} \approx 2 \text{ W.K}^{-1}.\text{m}^{-1}$ . When plotted in the form  $\kappa(T^{-1})$ , linear behaviors are observed up to 600 K. They are characteristic of phonon dominated thermal conductivities. This is also consistent with the very low  $\kappa_{\text{el}}$  values, calculated from the Wiedemann-Franz law (See corresponding curves in Fig. 9), which represent less than 10% of the total thermal conductivity over the whole temperature range.

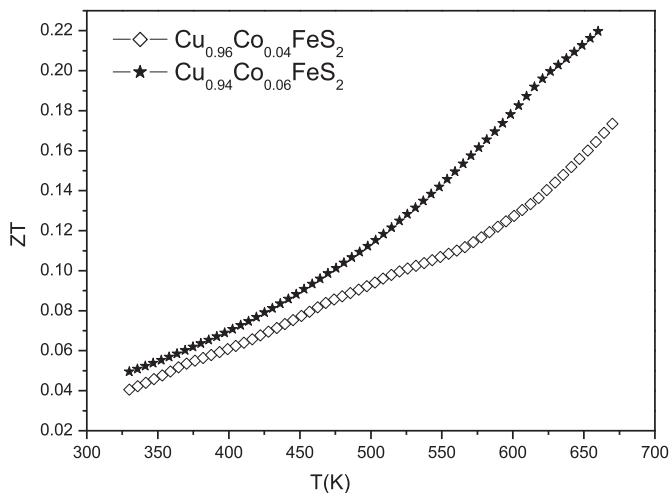


Fig. 10.  $T$  dependence of the figure of merit  $ZT$  for  $\text{Cu}_{0.96}\text{Co}_{0.04}\text{FeS}_2$  and  $\text{Cu}_{0.94}\text{Co}_{0.06}\text{FeS}_2$  densified by SPS.

Combining PF and  $\kappa$ , the corresponding values of the dimensionless figures of merit  $ZT$  were calculated (Fig. 10). At 675 K, a highest  $ZT$  value of 0.22 is achieved for  $\text{Cu}_{0.94}\text{Co}_{0.06}\text{FeS}_2$ .

#### 4. Discussion and concluding remarks

The present  $\kappa$  values, very similar for  $\text{Cu}_{0.96}\text{Co}_{0.04}\text{FeS}_2$  and  $\text{Cu}_{0.94}\text{Co}_{0.06}\text{FeS}_2$ , with  $\kappa_{400\text{K}} \approx 3.5 \text{ W.K}^{-1}.\text{m}^{-1}$ , are smaller than the values reported in Ref. [4] for  $\text{Cu}_{0.97}\text{Zn}_{0.03}\text{FeS}_2$  ( $x = 0.03$  and  $0.05$ ) which were all around  $5\text{--}6 \text{ W.K}^{-1}.\text{m}^{-1}$  at 400 K. At 575 K, for the present  $\text{Cu}_{1-x}\text{Co}_x\text{FeS}_2$  samples, they are close to the values given in Ref. [1] for sulfur deficient  $\text{CuFeS}_{2-x}$  with  $x \approx 0.15$ . Such a similarity for the  $\kappa$  values of the present Co-substituted  $\text{CuFeS}_2$  dense samples with the best values observed for S deficient  $\text{CuFeS}_2$  samples demonstrates the efficiency of the Co substitution for Cu to reduce the lattice part of the thermal conductivity. The very close values of  $\kappa$  for the  $x = 0.04$  and  $x = 0.06$  compounds are consistent with the fact that the lattice contribution is dominating.

The role of cobalt could result from its magnetic character as compared to zinc in  $\text{Cu}_{1-x}\text{Zn}_x\text{FeS}_2$ . More work would be needed to demonstrate a change in the magnetic properties. Finally, the best  $ZT$  value, 0.22 at 675 K is equivalent to the highest  $ZT$  values reported for materials derived from  $\text{CuFeS}_2$ , the highest value having been reported for a S-deficient compound,  $\text{CuFeS}_{1.80}$ , with  $ZT = 0.21$  at 573 K [1]. The present results suggest that by combining Co for Cu substitution and S deficiency, even highest  $ZT$  values should be reached.

#### Acknowledgments

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